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November 2013

## **FDP027N08B**

# N-Channel PowerTrench<sup>®</sup> MOSFET 80 V, 223 A, 2.7 m $\Omega$

#### **Features**

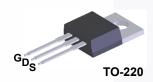
- $R_{DS(on)}$  = 2.21 m $\Omega$  ( Typ.) @  $V_{GS}$  = 10 V,  $I_D$  = 100 A
- Low FOM R<sub>DS(on)</sub> \* Q<sub>G</sub>
- Low Reverse-Recovery Charge, Q<sub>rr</sub> = 112 nC
- · Soft Reverse-Recovery Body Diode
- Enables High Efficiency in Synchronous Rectification
- · Fast Switching Speed
- · 100% UIL Tested
- · RoHS Compliant

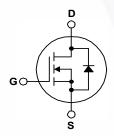
#### Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's PowerTrench® process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

### **Applications**

- · Synchronous Rectification for ATX / Server / Telecom PSU
- · Battery Protection Circuit
- · Motor Drives and Uninterruptible Power Supplies





#### **MOSFET Maximum Ratings** T<sub>C</sub> = 25°C unless otherwise noted.

Symbol		FDP027N08B_F102	Unit	
$V_{DSS}$	Drain to Source Voltage		80	V
$V_{GSS}$	Gate to Source Voltage		±20	V
		- Continuous (T <sub>C</sub> = 25°C, Silicon Limited)	223*	
I <sub>D</sub>	Drain Current	- Continuous (T <sub>C</sub> = 100°C, Silicon Limited)	158*	Α
		- Continuous (T <sub>C</sub> = 25°C, Package Limited)	120	Ī
I <sub>DM</sub>	Drain Current	Drain Current - Pulsed (Note 1)		Α
E <sub>AS</sub>	Single Pulsed Avalanche Energy	Single Pulsed Avalanche Energy (Note 2)		mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	6.0	V/ns
D	Payer Dissipation	$(T_C = 25^{\circ}C)$	246	W
$P_{D}$	Power Dissipation	- Derate Above 25°C	1.64	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperat	-55 to +175	°C	
T <sub>L</sub>	Maximum Lead Temperature for	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		

<sup>\*</sup>Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 120 A.

#### **Thermal Characteristics**

Symbol	Parameter	FDP027N08B_F102	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.61	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	°C/VV

## **Package Marking and Ordering Information**

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDP027N08B_F102	FDP027N08B	TO-220	Tube	N/A	N/A	50 units

## **Electrical Characteristics** $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	cteristics					
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$	80	-	-	V
ΔBV <sub>DSS</sub> / ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D$ = 250 μA, Referenced to 25°C	-	0.05	-	V/°C
1	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 64 V, V <sub>GS</sub> = 0 V	-	-	1	
I <sub>DSS</sub> Zero Gate Voltage Drain Current	$V_{DS} = 64 \text{ V}, T_{C} = 150^{\circ}\text{C}$	-	-	500	μА	
I <sub>GSS</sub>	Gate to Body Leakage Current	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V	-	-	±100	nA

#### On Characteristics

$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2.5	-	4.5	V
R <sub>DS(on)</sub>	Static Drain to Source On Resistance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 100 A	-	2.21	2.7	$m\Omega$
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 100 A	-	227	-	S

## **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance	V 40.V V 0.V	-	10170	13530	pF
C <sub>oss</sub>	Output Capacitance	$V_{DS} = 40 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1  MHz	-	1670	2220	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	-		35	-	pF
C <sub>oss</sub> (er)	Engry Related Output Capacitance	V <sub>DS</sub> = 40 V, V <sub>GS</sub> = 0 V	-	3025	-	pF
Q <sub>g(tot)</sub>	Total Gate Charge at 10V		-	137	178	nC
$Q_{gs}$	Gate to Source Gate Charge V <sub>DS</sub> = 40 V, V <sub>GS</sub> = 10 V,		-	56	-	nC
Q <sub>gs2</sub>	Gate Charge Threshold to Plateau	I <sub>D</sub> = 100A	-	25	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge	(Note 4)	-	28	-	nC
ESR	Equivalent Series Resistance (G-S)	f = 1 MHz	-	2.4	-	Ω

#### **Switching Characteristics**

t <sub>d(on)</sub>	Turn-On Delay Time			-	47	104	ns
t <sub>r</sub>	Turn-On Rise Time	$V_{DD} = 40 \text{ V}, I_{D} = 100 \text{ A},$		-/	66	142	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, R_{G} = 4.7 \Omega$		-	87	184	ns
t <sub>f</sub>	Turn-Off Fall Time		(Note 4)	/ -	41	92	ns

#### **Drain-Source Diode Characteristics**

I <sub>S</sub>	Maximum Continuous Drain to Source Diode Forward Current	-	-	223*	Α
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode Forward Current		-	892	Α
$V_{SD}$	Drain to Source Diode Forward Voltage $V_{GS} = 0 \text{ V}, I_{SD} = 10$	0 A -	-	1.3	V
t <sub>rr</sub>	Reverse Recovery Time $V_{GS} = 0 \text{ V}, V_{DD} = 4$	0 V, I <sub>SD</sub> = 100 A, -	80	-	ns
Q <sub>rr</sub>	Reverse Recovery Charge $dI_F/dt = 100 A/\mu s$	-	112	-	nC

#### Notes:

- 1. Repetitive rating: pulse-width limited by maximum junction temperature.
- 2. L = 3 mH, I $_{AS}$  = 24.72 A, R $_{G}$  = 25  $\Omega$ , starting T $_{J}$  = 25°C.
- 3. I\_{SD}  $\leq$  100 A, di/dt  $\leq$  200 A/µs, V\_DD  $\leq$  BV\_DSS, starting T\_J = 25°C.
- 4. Essentially independent of operating temperature typical characteristics.

## **Typical Performance Characteristics**

Figure 1. On-Region Characteristics

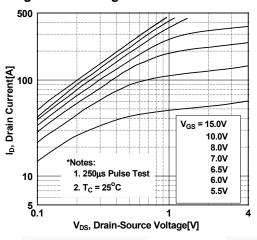


Figure 3. On-Resistance Variation vs.

Drain Current and Gate Voltage

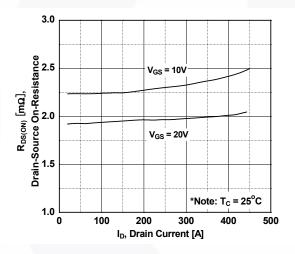


Figure 5. Capacitance Characteristics

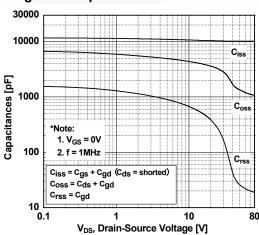


Figure 2. Transfer Characteristics

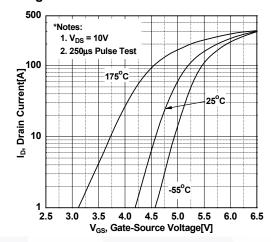


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

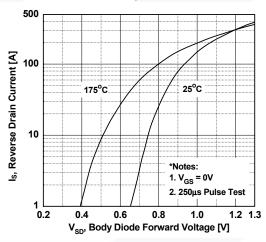
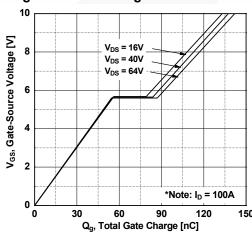


Figure 6. Gate Charge Characteristics



#### **Typical Performance Characteristics** (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

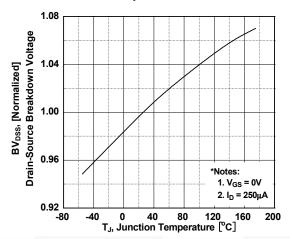


Figure 9. Maximum Safe Operating Area

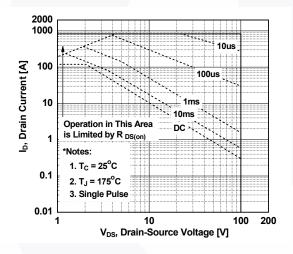


Figure 11. Eoss vs. Drain to Source Voltage

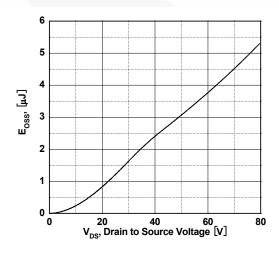


Figure 8. On-Resistance Variation vs. Temperature

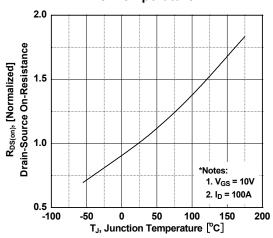


Figure 10. Maximum Drain Current vs. Case Temperature

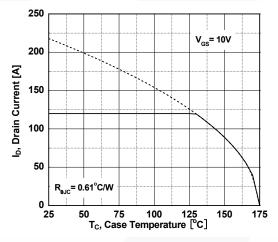
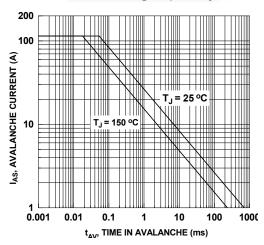
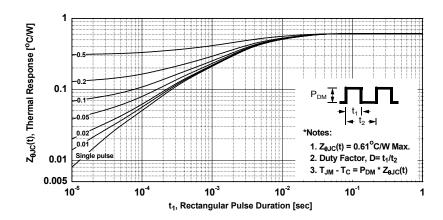


Figure 12. Unclamped Inductive Switching Capability



## **Typical Performance Characteristics** (Continued)





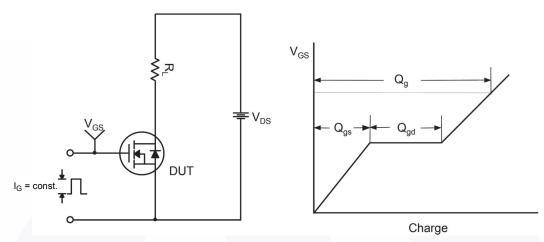


Figure 14. Gate Charge Test Circuit & Waveform

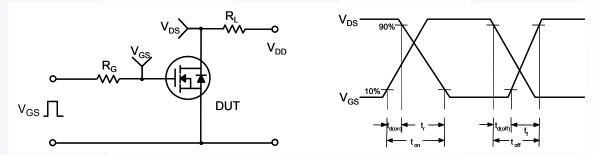


Figure 15. Resistive Switching Test Circuit & Waveforms



Figure 16. Unclamped Inductive Switching Test Circuit & Waveforms

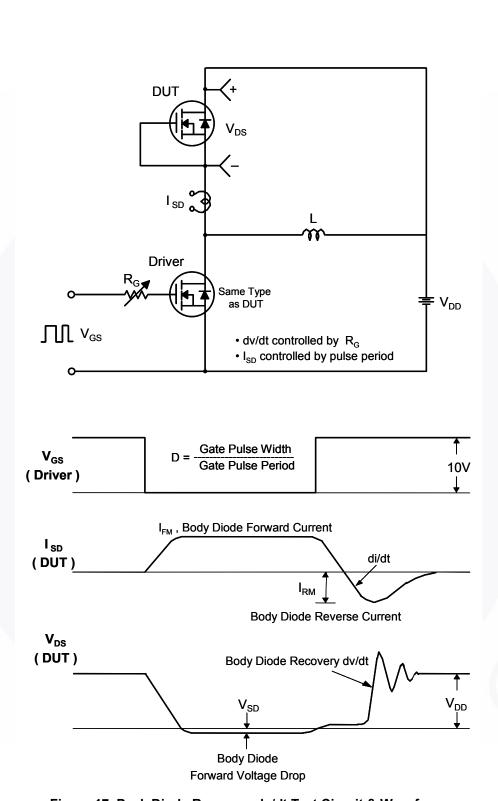


Figure 17. Peak Diode Recovery dv/dt Test Circuit & Waveforms

#### **Mechanical Dimensions**

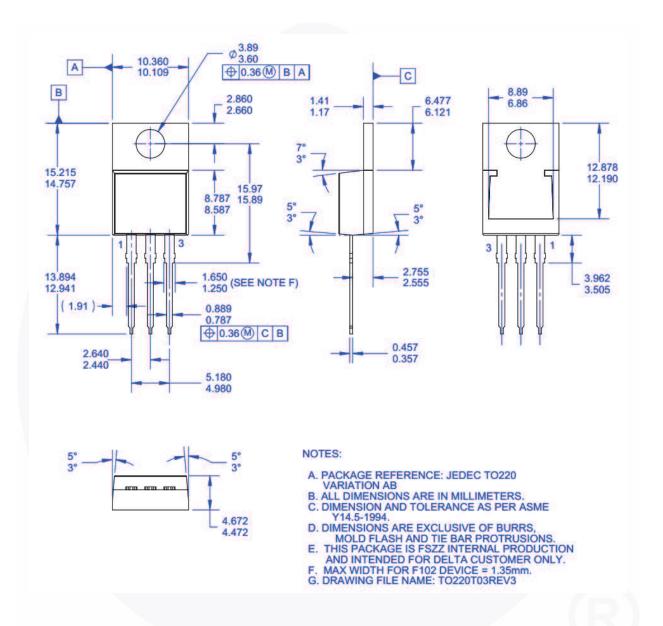


Figure 18. TO-220, Molded, 3-Lead, Jedec Variation AB (Delta)

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